



Attorney's Docket No. 07977-242001 / US3586

THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Ohnuma, et al. Art Unit : 1765
Serial No.: 09/050,182 Examiner : R. Kunemund
Filed : March 26, 1998
Title : METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE

BOX AF
Commissioner for Patents
Washington, D.C. 20231

RESPONSE

In response to the action mailed April 3, 2001, please
amend the application as follows:

In the claims:

Please amend claims 1, 9, 17, 25, 45 and 52 as follows:

Sub D1
C1
1. (Three Times Amended) A method of manufacturing a
semiconductor device including at least a thin film transistor,
said method comprising the steps of:
forming an amorphous semiconductor film comprising
silicon over a substrate;

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this
correspondence is being deposited with the
United States Postal Service as first class mail
with sufficient postage on the date indicated
below and is addressed to the Commissioner for
Patents, Washington, D.C. 20231.

August 3, 2001
Date of Deposit

Signature

Nancy Grant
Typed or Printed Name of Person Signing
Certificate

RECEIVED
AUG 14 2001
TC 1700